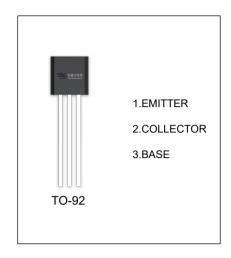


# MPS2907A TRANSISTOR (PNP)

## **FEATURES**

• Complementary NPN Type available (MPS2222A)



#### **ORDERING INFORMATION**

| Part Number | Package | Packing Method | Pack Quantity |
|-------------|---------|----------------|---------------|
| MPS2907A    | TO-92   | Bulk           | 1000pcs/Bag   |
| MPS2907A-TA | TO-92   | Таре           | 2000pcs/Box   |

## MAXIMUM RATINGS (Ta=25℃ unless otherwise noted)

| Symbol                           | Parameter  | Value    | Unit  |
|----------------------------------|--|----------|-------|
| V <sub>CBO</sub>                 | Collector-Base Voltage                           | -60      | V     |
| V <sub>CEO</sub>                 | Collector-Emitter Voltage                        | -60      | V     |
| V <sub>EBO</sub>                 | Emitter-Base Voltage                             | -5       | V     |
| Ic                               | Collector Current -Continuous                    | -600     | mA    |
| P <sub>D</sub>                   | Collector Power Dissipation                      | 625      | mW    |
| R <sub>θ</sub> JA                | Thermal Resistance from Junction to Ambient      | 200      | °C /W |
| T <sub>J</sub> ,T <sub>stg</sub> | Operation Junction and Storage Temperature Range | -55~+150 | °C    |



# $T_a$ =25 $^{\circ}$ C unless otherwise specified

| Parameter                            | Symbol               | Test conditions                                      | Min | Тур | Max   | Unit |
|--------------------------------------|----------------------|--|-----|-----|-------|------|
| Collector-base breakdown voltage     | V <sub>(BR)CBO</sub> | I <sub>C</sub> =-10μA,I <sub>E</sub> =0              | -60 |     |       | V    |
| Collector-emitter breakdown voltage  | V <sub>(BR)CEO</sub> | I <sub>C</sub> =-10mA,I <sub>B</sub> =0              | -60 |     |       | V    |
| Emitter-base breakdown voltage       | V <sub>(BR)EBO</sub> | I <sub>E</sub> =-10μA,I <sub>C</sub> =0              | -5  |     |       | V    |
| Collector cut-off current            | I <sub>CBO</sub>     | V <sub>CB</sub> =-50V,I <sub>E</sub> =0              |     |     | -10   | n A  |
| Collector cut-off current            | I <sub>CEX</sub>     | V <sub>CE</sub> =-30V,V <sub>EB(off)</sub> =-0.5V    |     |     | -50   | nA   |
| Emitter cut-off current              | I <sub>EBO</sub>     | V <sub>EB</sub> =-3V,I <sub>C</sub> =0               |     |     | -10   | nA   |
|                                      | h <sub>FE(1)</sub>   | V <sub>CE</sub> =-10V,I <sub>C</sub> =-0.1mA         | 78  |     |       |      |
| DC current gain                      | h <sub>FE(2)</sub>   | V <sub>CE</sub> =-10V,I <sub>C</sub> =-150mA         | 100 |     | 300   |      |
|                                      | h <sub>FE(3)</sub>   | V <sub>CE</sub> =-10V,I <sub>C</sub> =-500mA         | 52  |     |       |      |
| Collector-emitter saturation voltage | V <sub>CE(sat)</sub> | I <sub>C</sub> =-150mA,I <sub>B</sub> =-15mA         |     |     | -0.4  | V    |
|                                      | V <sub>CE(sat)</sub> | I <sub>C</sub> =-500mA,I <sub>B</sub> =-50mA         |     |     | -0.67 | V    |
| Base-emitter saturation voltage      | V <sub>BE(sat)</sub> | I <sub>C</sub> =-150mA,I <sub>B</sub> =-15mA         |     |     | -1    | V    |
|                                      | $V_{BE(sat)}$        | I <sub>C</sub> =-500mA,I <sub>B</sub> =-50mA         |     |     | -1.2  | V    |
| Transition frequency                 | f <sub>T</sub>       | V <sub>CE</sub> =-20V,I <sub>C</sub> =-50mA,f=100MHz | 200 |     |       | MHz  |
| Delay time                           | t <sub>d</sub>       | Vcc=-30V,Ic=-150mA,                                  |     |     | 10    | ns   |
| Rise time                            | t <sub>r</sub>       | I <sub>B1</sub> =-I <sub>B2</sub> =-15mA             |     |     | 25    | ns   |
| Storage time                         | ts                   | V <sub>CC</sub> =-6V,Ic=-150mA,                      |     |     | 225   | ns   |
| Fall time                            | $t_f$                | I <sub>B1</sub> =-I <sub>B2</sub> =-15mA             |     |     | 60    | ns   |

## **CLASSIFICATION OF h**<sub>FE(2)</sub>

| Rank  | L       | Н       |
|-------|---------|---------|
| Range | 100-200 | 200-300 |



